



### TLC27L1, TLC27L1A, TLC27L1B

#### **CMOS LOW POWER OPERATIONAL AMPLIFIERS**

#### Description

The TLC27L1 operational amplifier combines a wide range of input offset-voltage grades with low offset-voltage drift and high input impedance. The TLC27L1 is a low-bias version of the TLC271 programmable amplifier.

Three offset-voltage grades are available, ranging from the low-cost TLC27L1 (10mV) to the TLC27L1B (2mV) low-offset version. The devices are offered in both commercial and industrial operating temperature ranges.

The extremely high input impedance and low bias currents, in conjunction with good common-mode rejection and supply voltage rejection, make these devices a good choice for new state-of-the-art designs as well as for upgrading existing designs.

The devices also exhibit low-voltage single-supply operation, with a common-mode input-voltage range including the negative rail.

#### Features

 Wide range of supply voltages over specified temperature range:

0°C to +70°C . . . 3 V to 16 V

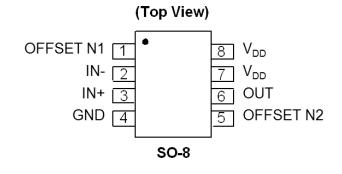
–40°C to +85°C . . . 4 V to 16 V

- Single-Supply Operation
- Common-Mode Input Voltage Range Extends Below the Negative Rail
- Low Noise:

68nV/√Hz typical @ f = 1kHz

- Output Voltage Range Includes Negative Rail
- High Input Impedance
- Designed-In Latch-Up Immunity
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### Pin Assignments



#### Applications

The TLC27L1 is the low power version of the TLC271. It offers low power for applications requiring long battery life. For applications that require more performance consider the TLC271.

The TLC27L1 is well suited to many consumer audio, industrial and other low power applications. Consider carefully the bandwidth and slew rate requirements for a specific application.

- Audio Microphone Preamplifier Filtering – Equalizers
- Signal Amplification Industrial Power Supply
  - Instrumentation
- Metering
- Medical Portable Meters and Measurement Instrumentation

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



### **Ordering Information**

	Deekere	Offeet	Operating	Paakaging	13" Tape a	13" Tape and Reel			
Device	Package Code	Offset Voltage	Temperature Range	Packaging (Note 4)	Quantity	Part Number Suffix			
TLC27L1CS-13	S	10mV	0 to +70°C	SO-8	2500/Tape & Reel	-13			
TLC27L1ACS-13	S	5mV	0 to +70°C	SO-8	2500/Tape & Reel	-13			
TLC27L1BCS-13	S	2mV	0 to +70°C	SO-8	2500/Tape & Reel	-13			
TLC27L1IS-13	S	10mV	-40 to +85°C	SO-8	2500/Tape & Reel	-13			
TLC27L1AIS-13	S	5mV	-40 to +85°C	SO-8	2500/Tape & Reel	-13			
TLC27L1BIS-13	S	2mV	-40 to +85°C	SO-8	2500/Tape & Reel	-13			

Note:

4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

#### **Pin Descriptions**

Pin Name	Pin Number	Description
OFFSET N1	1	Offset Control Inverting Input
IN-	2	Inverting Input
IN+	3	Non-Inverting Input
GND	4	Ground
OFFSET N2	5	Offset Control Non-Inverting Input
OUT	6	Output
V <sub>DD</sub>	7	Supply
V <sub>DD</sub>	8	Supply



### Absolute Maximum Ratings (Notes 5, 6, 7, 8, 9)

Symbol	Parameter		Rating	Unit
V <sub>DD</sub>	Supply Voltage: (Note 6)		18	V
V <sub>ID</sub>	Differential Input Voltage (Note 7)	Differential Input Voltage (Note 7)		V
V <sub>IN</sub>	Input Voltage Range (either input)		-0.3 to V <sub>DD</sub>	V
I <sub>IN</sub>	Input Current		±5	mA
lo	Output current		±30	mA
	Output Short-Circuit to GND (Note	8)	Continuous	_
PD	Power Dissipation (Note 9)		1065	mW
-		C Grade	0 to +70	
T <sub>A</sub>	Operating Temperature Range	I Grade	-40 to +85	- °C
TJ	Operating Junction Temperature		150	°C
T <sub>ST</sub>	Storage Temperature Range		-65 to +150	°C
ESD HBM	Human Body Model ESD Protectio	n (1.5kΩ in series with 100pF)	1.5	kV

Notes: 5. Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only; Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values, except differential voltages, are with respect to ground.
 Differential input voltages are at IN+ with respect to IN-.

8. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

9. For operating at high temperatures, the TLC27L1 must be derated 8.5mW/°C to zero based on a +150°C maximum junction temperature and a thermal resistance of +117 °C/W when the device is soldered to a printed circuit board, operating in a still air ambient.

#### **Recommended Operating Conditions**

Symbol	Paramete	C g	rade	l gr	ade	Unit	
Symbol	Paramete	Min	Max	Min	Max	_	
V <sub>DD</sub>	Supply Voltage		3	16	4	16	V
V <sub>IC</sub>	Common Mode Input Voltage	$V_{DD} = 5V$	-0.2	3.5	-0.2	3.5	V
		$V_{DD} = 10V$	-0.2	8.5	-0.2	8.5	
T <sub>A</sub>	Operating Free Air Temperature	1	0	+70	-40	+85	°C



					TL	.C27L10	, TLC2	7L1AC,	TLC27L	1BC	
	Parameter		Conditions	TA	,	V <sub>DD</sub> = 5V	1		$V_{DD} = 10$	v	Unit
					Min	Тур	Max	Min	Тур.	Max	
		TI 007140		+25°C	—	1.1	10	—	1.1	10	
		TLC27L1C	$V_{0} = 1.4V$	0 to +70°C	—		12	—		12	
			$V_{IC} = 0V$	+25 <sup>°</sup> C		0.9	5	—	0.9	5	
V <sub>IO</sub>	Input Offset Voltage	TLC27L1AC	R <sub>s</sub> = 50Ω	0 to +70 <sup>°</sup> C	_	_	6.5	_		6.5	mV
		TLC27L1BC	$R_L = 1M\Omega$	+25 <sup>°</sup> C	—	0.24	2	—	0.26	2	
		TLC27L1BC		0 to +70 <sup>°</sup> C	_		3	_		3	
$\alpha_{\text{VIO}}$	Average Temperature Input Offset Voltage	e Coefficient of		+25 to +70°C		1.1			1		µV/°C
			$V_{O} = V_{DD}/2$ ,	+25 <sup>°</sup> C		0.1	60	—	0.1	60	
IIO	Input Offset Current	(Note 10)	$V_{IC} = V_{DD}/2$	+70 <sup>°</sup> C	—	7	300	—	8	300	pА
			$V_{O} = V_{DD}/2$ ,	+25 <sup>°</sup> C	—	0.6	60	—	0.7	60	
I <sub>IB</sub>	Input Bias Current (N	Note 10)	$V_{IC} = V_{DD}/2$	+70 <sup>°</sup> C	—	40	600	—	50	600	pА
				+25 <sup>°</sup> C	-0.2 to 4	-0.3 to 4.2		-0.2 to 9	-0.3 to 9.2	_	V
V <sub>ICR</sub>	Common Mode Input	Voltage (Note 11)		0°C to +70 <sup>°</sup> C	-0.2 to 3.5			-0.2 to 8.5			V
				+25 <sup>°</sup> C	3.2	4.1	_	8	8.9		-
V <sub>он</sub>	High Level Output Vo	ltage	$V_{ID} = 100 \text{mV},$	0°C	3	4.1		7.8	8.9	_	V
			$R_L = 1M\Omega$	+70 <sup>°</sup> C	3	4.2		7.8	8.9	_	
			V 400 V	+25 <sup>°</sup> C	—	0	50	—	0	50	
Vol	Low Level Output Vo	Itage	$V_{ID} = -100 \text{mV},$	0 <sup>°</sup> C	—	0	50	—	0	50	mV
			$I_{OL} = 0$	+70 <sup>°</sup> C	—	0	50	—	0	50	
			D 4140	+25 <sup>°</sup> C	50	520		50	870		
$A_{VD}$	Large Signal Differen	tial Voltage Gain	R <sub>L</sub> = 1MΩ (Note 12)	0°C	50	700		50	1030		V/mV
				+70 <sup>°</sup> C	50	380		50	660		
				+25 <sup>°</sup> C	65	94		65	97		
CMRR	Common Mode Reject	ction Ratio	$V_{IC} = V_{ICRmin}$	0 <sup>°</sup> C	60	95		60	97		dB
				+70 <sup>°</sup> C	60	95		60	97		
	Supply Voltage Reject	tion Potic	$V_{DD} = 5V$ to	+25 <sup>°</sup> C	70	97		70	97		
$\mathbf{k}_{\text{SVR}}$	$(\Delta V_{DD}/\Delta V_{IO})$		10V	0°C	60	97		60	97		dB
			$V_0 = 1.4V$	+70 <sup>°</sup> C	60	98		60	98		
			$V_{O} = V_{DD}/2,$	+25 <sup>°</sup> C	—	10	17	—	14	23	
$I_{DD}$	Supply Current		$V_{IC} = V_{DD}/2,$	0°C		12	21		18	33	μΑ
			No Load	+70 <sup>°</sup> C		8	14		11	20	

Notes: 10. The typical values of input bias current and input offset current below 5pA were calculated.

11. This range also applies to each input individually.

12. At  $V_{DD}$  = 5V,  $V_O$  = 0.25V to 2V; at  $V_{DD}$  = 10V,  $V_O$  = 1V to 6V.



					٦	LC27L1	I, TLC2	7L1AI, "	TLC27L1	BI	
	Parameter		Conditions	TA		V <sub>DD</sub> = 5V	/		$V_{DD} = 10$	v	Unit
					Min	Тур	Max	Min	Тур.	Max	
		TI 007141		+25°C	_	1.1	10		1.1	10	
		TLC27L1I		-40° to 85°C	_	_	13	—	_	13	
V	lanut Offerst Velteres		$V_{IC} = 0V$	+25°C	_	0.9	5	_	0.9	5	
V <sub>IO</sub>	Input Offset Voltage	TLC27L1AI	R <sub>s</sub> = 50Ω	-40° to +85°C			7			7	mV
			$R_L = 1M\Omega$	+25°C		0.24	2		0.26	2	
		TLC27L1BI		-40° to +85°C			3.5			3.5	
$\alpha_{VIO}$	Average Temperature Input Offset Voltage	Coefficient of	_	+25°C to +85°C		1.1			1		µV/°C
			$V_{\rm O} = V_{\rm DD}/2$	+25°C	_	0.1	60		0.1	60	
I <sub>IO</sub>	Input Offset Current (N	lote 13)	$V_{IC} = V_{DD}/2$	+85°C		24	1000		26	1000	pА
_			$V_0 = V_{DD}/2$	+25°C	—	0.6	60	—	0.7	60	
I <sub>IB</sub>	Input Bias Current (No	te 13)	$V_{IC} = V_{DD}/2$	+85°C	—	200	2000		220	2000	рА
	Common Mode Input V	oltage (Note		+25°C	-0.2 to 4	-0.3 to 4.2	_	-0.2 to 9	-0.3 to 9.2	—	V
V <sub>ICR</sub>	14)		_	-40° to +85°C	-0.2 to 3.5			-0.2 to 8.5		_	V
				+25°C	3	4.1	_	8	8.9		
V <sub>он</sub>	ligh Level Output Voltage	age	$V_{ID} = 100 \text{mV}, \text{R}_{L} =$	-40°C	3	4.1	—	7.8	8.9	—	V
		-	1ΜΩ	+85°C	3	4.2		7.8	8.9	—	
				+25°C	—	0	50	—	0	50	
V <sub>OL</sub>	Low Level Output Volta	ige	$V_{ID} = -100 \text{mV},$	-40°C	_	0	50		0	50	mV
			$I_{OL} = 0$	+85°C		0	50		0	50	
			D 4140	+25°C	50	520	—	50	870	_	
A <sub>VD</sub>	Large Signal Differentia	al Voltage	$R_{L} = 1M\Omega$	-40°C	50	900		50	1550	_	V/mV
	Gain		(Note 15)	+85°C	50	330		50	585	—	
				+25°C	65	94		65	97	—	
CMRR	Common Mode Rejecti	on Ratio	$V_{IC} = V_{ICRmin}$	-40°C	60	95		60	97	—	dB
				+85°C	60	95	_	60	98		
	Supply Voltage Rejecti	on Potio	$V_{DD} = 5V$ to 10V	+25°C	70	97	—	70	97		
<b>k</b> <sub>SVR</sub>	Supply voltage Rejecti $(\Delta V_{DD}/\Delta V_{IO})$	UII RaliU	$V_{DD} = 5V 10 10V$ $V_{O} = 1.4V$	-40°C	60	97		60	97		dB
			VU - 1.4V	+85°C	60	98		60	98		
			$V_0 = V_{DD}/2$	+25°C	—	10	17		14	23	
I <sub>DD</sub>	Supply Current		$V_{IC} = V_{DD}/2$	-40°C	—	16	27	—	25	43	μA
			No load	+85°C		17	13		10	18	

Notes: 13. The typical values of input bias current and input offset current below 5pA were calculated.

14. This range also applies to each input individually.

15. At  $V_{DD}$  = 5V,  $V_O$  = 0.25V to 2V; at  $V_{DD}$  = 10V,  $V_O$  = 1V to 6V.



00 -	5V							
	Parameter	с	onditions	TA	TLC2	7L1C, TLC27 TLC27L1BC	L1AC,	Unit
					Min	Тур	Max	
				+25°C	—	0.03	_	
		$R_L = 1M\Omega$	$V_{I(PP)} = 1V$	0°C	—	0.04	_	
0.0		C <sub>L</sub> = 20pF		+70°C	—	0.03	_	
SR	Slew Rate at Unity Gain	See		+25°C	_	0.03	_	V/µs
		Figure 31	$V_{I(PP)} = 2.5V$	0°C	_	0.03	_	
				+70°C		0.02	_	
Vn	Equivalent Input Noise Voltage	$F = 1kHz, R_s = 20\Omega$ See Figure 32		+25°C		68	_	nV/√Hz
				+25°C		5		
Вом	Maximum Output Swing		= 20pF, R <sub>L</sub> = 1MΩ	0°C		6		kHz
	Bandwidth	See Figure 3	1	+70°C		4.5	_	
				+25°C		85		
B1	Unity Gain Bandwidth	$V_{I} = 10mV, C$		0°C		100	_	MHz
		See Figure 3	3	+70°C	_	65		1
		$F = B_1, V_1 = 10mV, C_L = 20pF$ See Figure 33		+25°C	_	34°		
фm	φ <sub>m</sub> Phase Margin			0°C		36°		
• • • •	5			+70°C		30°		
V <sub>DD</sub> = 10	V	1		I				
					TLC2	TLC27L1C, TLC27L1AC,		
	Parameter	Conditions		TA	TLC27L1BC			Unit
					Min	Тур	Max	
				+25°C	—	0.05		
		R <sub>L</sub> = 1MΩ,	$V_{I(PP)} = 1V$	+25°C 0°C		0.05 0.05		
0.5		R <sub>L</sub> = 1MΩ, C <sub>L</sub> = 20pF	$V_{I(PP)} = 1V$					-
SR	Slew Rate at Unity Gain		V <sub>I(PP)</sub> = 1V	0°C		0.05		 V/μs
SR	Slew Rate at Unity Gain	$C_L = 20 pF$	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$	0°C +70°C		0.05 0.04		V/µs
SR	Slew Rate at Unity Gain	C∟ = 20pF See		0°C +70°C +25°C		0.05 0.04 0.04		 V/μs
SR Vn	Slew Rate at Unity Gain	C <sub>L</sub> = 20pF See Figure 31 F = 1kHz, R <sub>s</sub>	V <sub>I(PP)</sub> = 5.5V = 20Ω	0°C +70°C +25°C 0°C		0.05 0.04 0.04 0.05		V/µs nV/√Hz
	Equivalent Input Noise Voltage	$C_{L} = 20 pF$ See Figure 31 F = 1kHz, R <sub>s</sub> See Figure 3	V <sub>I(PP)</sub> = 5.5V = 20Ω	0°C +70°C +25°C 0°C +70°C		0.05 0.04 0.04 0.05 0.04		
Vn	Equivalent Input Noise Voltage Maximum Output Swing	$C_L = 20pF$ See Figure 31 $F = 1kHz, R_S$ See Figure 32 $V_0 = V_{OH}, C_L$	V <sub>I(PP)</sub> = 5.5V = 20Ω 2 = 20pF, R <sub>L</sub> = 1MΩ	0°C +70°C +25°C 0°C +70°C +25°C		0.05 0.04 0.04 0.05 0.04 68 1		
	Equivalent Input Noise Voltage	$C_{L} = 20 pF$ See Figure 31 F = 1kHz, R <sub>s</sub> See Figure 3	V <sub>I(PP)</sub> = 5.5V = 20Ω 2 = 20pF, R <sub>L</sub> = 1MΩ	0°C +70°C +25°C 0°C +70°C +25°C +25°C 0°C		0.05 0.04 0.04 0.05 0.04 68 1 1.3		nV/√Hz
Vn	Equivalent Input Noise Voltage Maximum Output Swing	$C_{L} = 20 pF$ See Figure 31 $F = 1 kHz, R_{S}$ See Figure 3: $V_{O} = V_{OH}, C_{L}$ See Figure 3	$V_{I(PP)} = 5.5V$ = 20 $\Omega$ = 20pF, R <sub>L</sub> = 1M $\Omega$	0°C +70°C +25°C 0°C +70°C +25°C +25°C 0°C +70°C		0.05 0.04 0.04 0.05 0.04 68 1		nV/√Hz
Vn	Equivalent Input Noise Voltage Maximum Output Swing Bandwidth	$C_L = 20pF$ See Figure 31 $F = 1kHz, R_S$ See Figure 3 $V_0 = V_{OH}, C_L$ See Figure 3 $V_I = 10mV, C$	$V_{I(PP)} = 5.5V$ = 20 $\Omega$ = 20pF, R <sub>L</sub> = 1M $\Omega$ 1	0°C +70°C +25°C 0°C +70°C +25°C +25°C 0°C +70°C +25°C		0.05 0.04 0.04 0.05 0.04 68 1 1.3 0.9		nV/√Hz
V <sub>n</sub> B <sub>OM</sub>	Equivalent Input Noise Voltage Maximum Output Swing	$C_{L} = 20 pF$ See Figure 31 $F = 1 kHz, R_{S}$ See Figure 3: $V_{O} = V_{OH}, C_{L}$ See Figure 3	$V_{I(PP)} = 5.5V$ = 20 $\Omega$ = 20pF, R <sub>L</sub> = 1M $\Omega$ 1	0°C +70°C +25°C 0°C +70°C +25°C +25°C 0°C +70°C +25°C 0°C +25°C 0°C		0.05 0.04 0.04 0.05 0.04 68 1 1.3 0.9 110 125		nV/√Hz kHz
V <sub>n</sub> B <sub>OM</sub>	Equivalent Input Noise Voltage Maximum Output Swing Bandwidth	$C_{L} = 20 pF$ See Figure 31 $F = 1 kHz, R_{S}$ See Figure 3: $V_{0} = V_{OH}, C_{L}$ See Figure 3: $V_{1} = 10 mV, C$ See Figure 3:	$V_{I(PP)} = 5.5V$ = 20 $\Omega$ = 20pF, R <sub>L</sub> = 1M $\Omega$ 1 L = 20pF	0°C +70°C +25°C 0°C +70°C +25°C 0°C +25°C 0°C +70°C +25°C 0°C +70°C		0.05 0.04 0.04 0.05 0.04 68 1 1.3 0.9 110 125 90		nV/√Hz kHz
V <sub>n</sub> B <sub>OM</sub>	Equivalent Input Noise Voltage Maximum Output Swing Bandwidth	$C_{L} = 20 pF$ See Figure 31 $F = 1 kHz, R_{S}$ See Figure 3: $V_{0} = V_{OH}, C_{L}$ See Figure 3: $V_{1} = 10 mV, C$ See Figure 3:	$V_{I(PP)} = 5.5V$ = 20 $\Omega$ = 20pF, R <sub>L</sub> = 1M $\Omega$ 1 L = 20pF 3 0mV, C <sub>L</sub> = 20pF	0°C +70°C +25°C 0°C +70°C +25°C +25°C 0°C +70°C +25°C 0°C +25°C 0°C		0.05 0.04 0.04 0.05 0.04 68 1 1.3 0.9 110 125		nV/√Hz kHz



Parameter			Conditions	T <sub>A</sub>	TLC2	7L1I, TLC27 TLC27L1BI		Unit
					Min	Тур	Max	
				+25°C	—	0.03	—	
		R <sub>L</sub> = 1MΩ	$V_{I(PP)} = 1V$	-40°	_	0.04	_	
0.5		$C_L = 20 pF$		+85°C	_	0.03	_	
SR	Slew Rate at Unity Gain	See		+25°C	_	0.03	_	V/µs
		Figure 31	$V_{I(PP)} = 2.5V$	-40°	_	0.04	_	
				+85°C	_	0.02	_	
Vn	Equivalent Input Noise Voltage	F = 1kHz, R <sub>s</sub> See Figure 32		+25°C	_	68	_	nV/√Hz
		$V_0 = V_{OH}, C_L = 20 \text{pF}, R_L = 1 \text{M}\Omega$		+25°C	—	5		
Вом	Maximum Output Swing			-40°	—	7		kHz
	Bandwidth	See Figure 31		+85°C		4		
		N 40 N 5	00-5	+25°C		85		
B <sub>1</sub>	Unity Gain Bandwidth	$V_1 = 10 \text{mV}, C_1$	•	-40°		130		MHz
		See Figure 33	5	+85°C	_	55	_	
		$F = B_1, V_1 = 10mV, C_L = 20pF \qquad See$ Figure 33		+25°C	_	34°	_	
фm	Phase Margin			-40°	_	38°	_	
				+85°C	_	28°	—	
/ <sub>DD</sub> = 10	)V							
					TLC27L1I, TLC27L1AI,			11-14
					TLC2	7L11, 1LC2/	'L1AI,	Unit
	Parameter		Conditions	TA	TLC2	TLC27L1BI		Unit
	Parameter		Conditions	T₄	Min			Unit
	Parameter		Conditions	<b>T</b> <sub>A</sub> +25°C		TLC27L1BI		Unit —
	Parameter	R <sub>L</sub> = 1MΩ	Conditions V <sub>I(PP)</sub> = 1V			TLC27L1BI Typ		Unit 
<u><u>C</u>P</u>				+25°C	Min —	TLC27L1BI Typ 0.05	Max —	-
SR	Parameter Slew Rate at Unity Gain	R <sub>L</sub> = 1MΩ		+25°C -40°	Min 	TLC27L1BI Typ 0.05 0.06	Max —	Unit 
SR		R <sub>L</sub> = 1MΩ C <sub>L</sub> = 20pF		+25°C -40° +85°C	Min 	TLC27L1BI Typ 0.05 0.06 0.03	Max 	-
SR		$R_L = 1M\Omega$ $C_L = 20pF$ See	V <sub>I(PP)</sub> = 1V	+25°C -40° +85°C +25°C	Min 	TLC27L1BI Typ 0.05 0.06 0.03 0.04	Max 	-
SR		$R_L = 1M\Omega$ $C_L = 20pF$ See	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ $= 20\Omega$	+25°C -40° +85°C +25°C -40°	Min 	TLC27L1BI Typ 0.05 0.06 0.03 0.04 0.05	Max 	-
	Slew Rate at Unity Gain	$R_L = 1M\Omega$ $C_L = 20pF$ See Figure 31 $F = 1kHz, R_S$ See Figure 32	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ $= 20\Omega$	+25°C -40° +85°C +25°C -40° +85°C	Min 	TLC27L1BI Typ 0.05 0.06 0.03 0.04 0.05 0.03	Max 	 - V/µs
	Slew Rate at Unity Gain Equivalent Input Noise Voltage Maximum Output Swing	$R_L = 1MΩ$ $C_L = 20pF$ See Figure 31 $F = 1kHz, R_S$ See Figure 32 $V_0 = V_{OH}, C_L = 1$	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ = 20Ω = 20pF, R <sub>L</sub> = 1MΩ	+25°C -40° +85°C +25°C -40° +85°C +25°C	Min — — — — —	Typ           0.05           0.06           0.03           0.04           0.05           0.03	Max 	 - V/µs
Vn	Slew Rate at Unity Gain	$R_L = 1M\Omega$ $C_L = 20pF$ See Figure 31 $F = 1kHz, R_S$ See Figure 32	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ = 20Ω = 20pF, R <sub>L</sub> = 1MΩ	+25°C -40° +85°C +25°C -40° +85°C +25°C +25°C	Min     	Typ           0.05           0.06           0.03           0.04           0.05           0.03           1	Max 	 V/μs  nV/√Hz
Vn	Slew Rate at Unity Gain Equivalent Input Noise Voltage Maximum Output Swing	$R_{L} = 1M\Omega$ $C_{L} = 20pF$ See Figure 31 $F = 1kHz, R_{S}$ See Figure 32 $V_{O} = V_{OH}, C_{L} =$ See Figure 31	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ $= 20\Omega$ $= 20pF, R_{L} = 1M\Omega$	+25°C -40° +85°C +25°C -40° +85°C +25°C +25°C +25°C -40°	Min 	Typ           0.05           0.06           0.03           0.04           0.05           0.03           1           1.4	Max 	 V/μs  nV/√Hz
Vn	Slew Rate at Unity Gain Equivalent Input Noise Voltage Maximum Output Swing	$R_{L} = 1M\Omega$ $C_{L} = 20pF$ See Figure 31 $F = 1kHz, R_{S}$ See Figure 32 $V_{O} = V_{OH}, C_{L}$ See Figure 31 $V_{I} = 10mV, C_{L}$	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ = 20Ω = 20pF, R <sub>L</sub> = 1MΩ = 20pF	+25°C -40° +85°C +25°C -40° +85°C +25°C +25°C +25°C -40° +85°C	Min — — — — — — — —	TLC27L1BI Typ 0.05 0.06 0.03 0.04 0.05 0.03 68 1 1.4 0.8	Max 	 V/μs  nV/√Hz
V <sub>n</sub> B <sub>OM</sub>	Slew Rate at Unity Gain Equivalent Input Noise Voltage Maximum Output Swing Bandwidth	$R_{L} = 1M\Omega$ $C_{L} = 20pF$ See Figure 31 $F = 1kHz, R_{S}$ See Figure 32 $V_{O} = V_{OH}, C_{L} =$ See Figure 31	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ = 20Ω = 20pF, R <sub>L</sub> = 1MΩ = 20pF	+25°C -40° +85°C +25°C -40° +85°C +25°C +25°C -40° +85°C +25°C	Min          -	Typ           0.05           0.06           0.03           0.04           0.05           0.03           68           1           1.4           0.8           110	Max 	V/µs nV/√Hz kHz
V <sub>n</sub> B <sub>OM</sub>	Slew Rate at Unity Gain Equivalent Input Noise Voltage Maximum Output Swing Bandwidth	$R_{L} = 1M\Omega$ $C_{L} = 20pF$ See Figure 31 $F = 1kHz, R_{S}$ See Figure 32 $V_{O} = V_{OH}, C_{L} =$ See Figure 31 $V_{I} = 10mV, C_{L}$ See Figure 33	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ $= 20\Omega$ $= 20\rho F, R_{L} = 1M\Omega$ $= 20\rho F$	+25°C -40° +85°C +25°C -40° +85°C +25°C +25°C -40° +85°C +25°C +25°C -40°	Min	Typ           0.05           0.06           0.03           0.04           0.05           0.03           68           1           1.4           0.8           110           155	Max 	V/µs nV/√Hz kHz
V <sub>n</sub> B <sub>OM</sub>	Slew Rate at Unity Gain Equivalent Input Noise Voltage Maximum Output Swing Bandwidth	$R_{L} = 1M\Omega$ $C_{L} = 20pF$ See Figure 31 $F = 1kHz, R_{S}$ See Figure 32 $V_{O} = V_{OH}, C_{L} =$ See Figure 31 $V_{I} = 10mV, C_{L}$ See Figure 33	$V_{I(PP)} = 1V$ $V_{I(PP)} = 5.5V$ = 20Ω = 20pF, R <sub>L</sub> = 1MΩ = 20pF	+25°C -40° +85°C +25°C -40° +85°C +25°C +25°C -40° +85°C +25°C -40° +85°C	Min	Typ           0.05           0.06           0.03           0.04           0.05           0.03           1.4           0.8           110           155           80	Max 	V/µs nV/√Hz kHz



# TLC27L1, TLC27L1A, TLC27L1B

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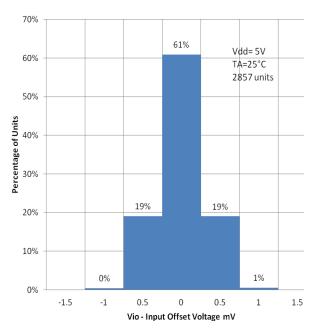
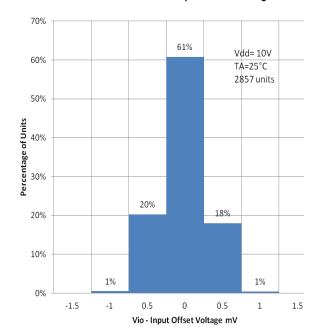


Figure 1

#### Distribution of TLC27L1 Input Offset Voltage



#### Distribution of TLC27L1 Input Offset Voltage

Figure 2

18

1б

V<sub>0H</sub>-High-Level Output Voltage-V

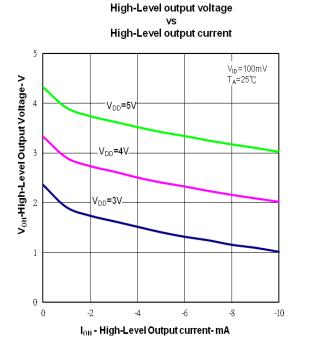
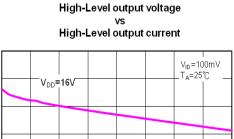
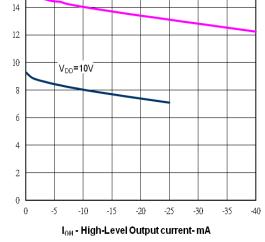


Figure 3









High-Level output voltage

### **Typical Performance Characteristics**

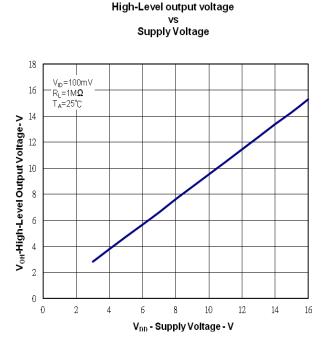


Figure 5

Low-level output voltage

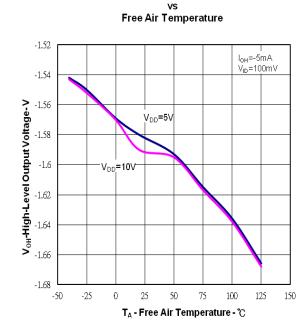
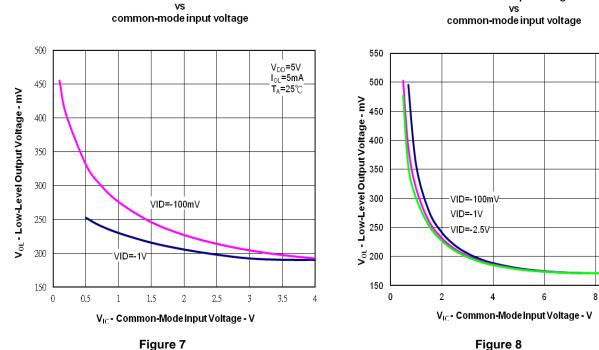


Figure 6

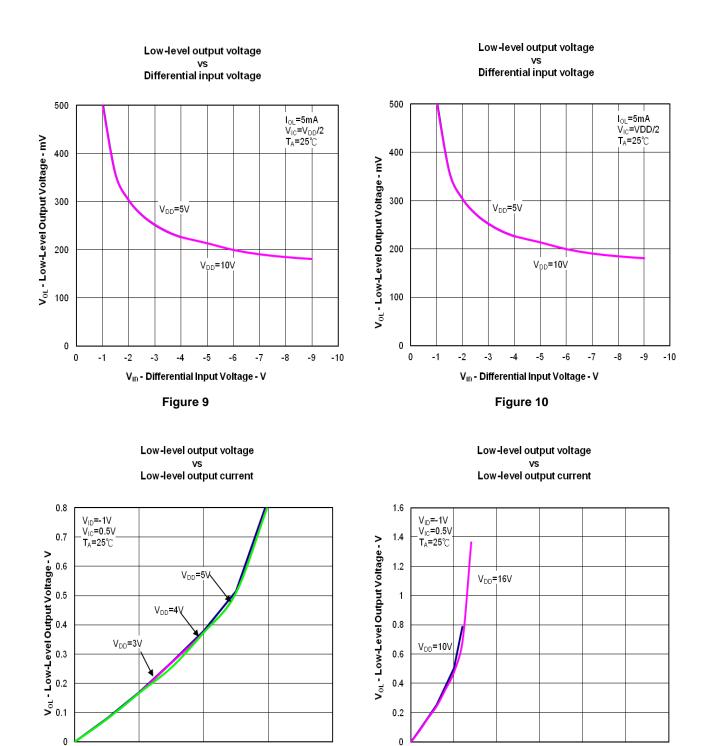
Low-level output voltage



10

V<sub>DD</sub>=10V -I<sub>OL</sub>=5mA -T<sub>A</sub>=25℃





2

4

Io1 - Low-Level Output Current - mA

Figure 11

6

8

0

5

10

15

Io1 - Low-Level Output Current - mA

Figure 12

20

25

30

0



Large-Signal Differential Voltage Amplification

#### **Typical Performance Characteristics**

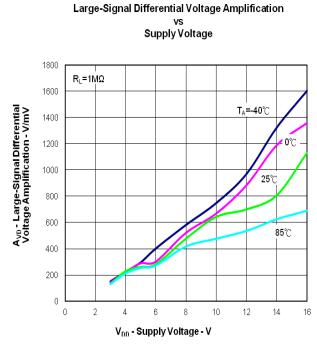
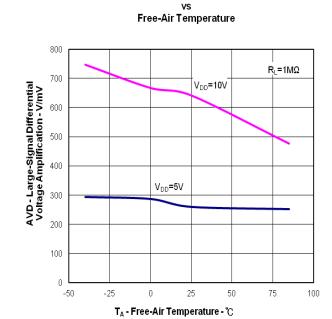


Figure 13



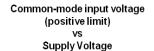




lιn

105

125



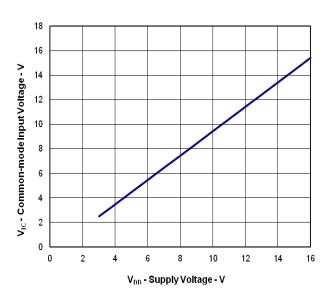


Figure 16

45

65

Figure 15

 $T_{\text{A}}$  - Free-Air Temperature -  $^{\circ}\!\mathrm{C}$ 

85

 $\mathbf{I}_{\mathrm{B}}$  and  $\mathbf{I}_{\mathrm{I0}}$  - Input Bias and Input Offset Current - pA

1000

900

800

700

600

500

400

300

200

100

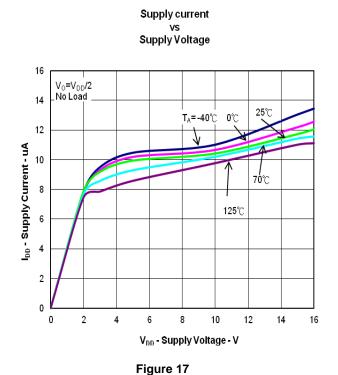
0

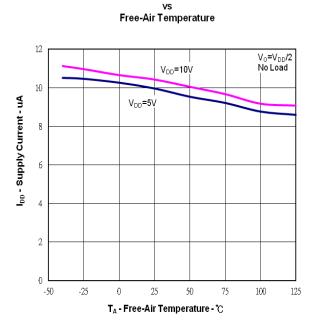
25

V<sub>DD</sub>=10V

V<sub>IC</sub>=5V



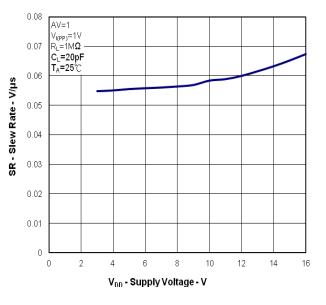




Supply current

Figure 18

Slew rate vs



Slew Rate

vs Supply Voltage

Figure 19

Free-Air Temperature

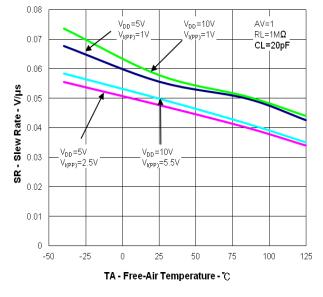
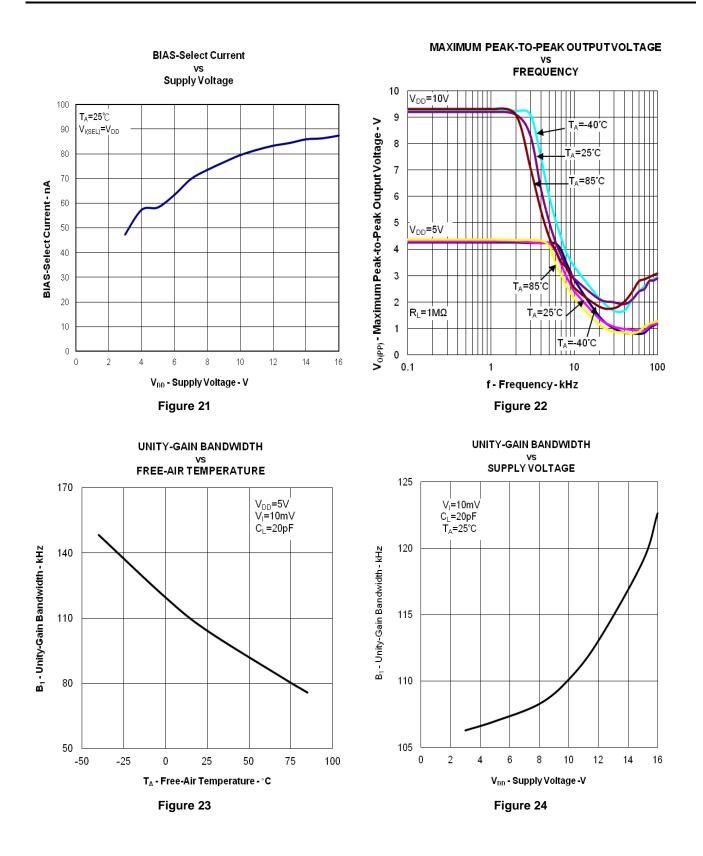
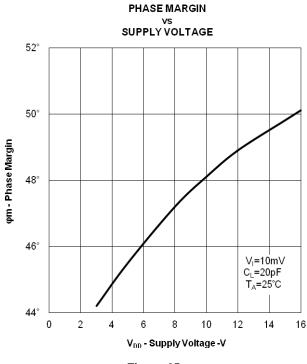


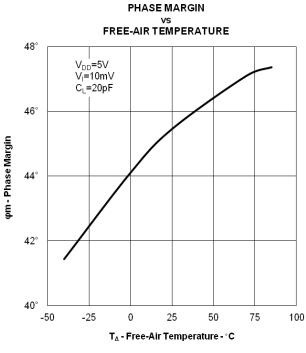
Figure 20













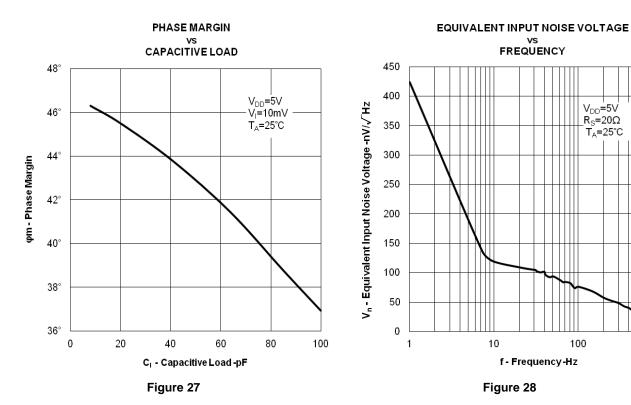
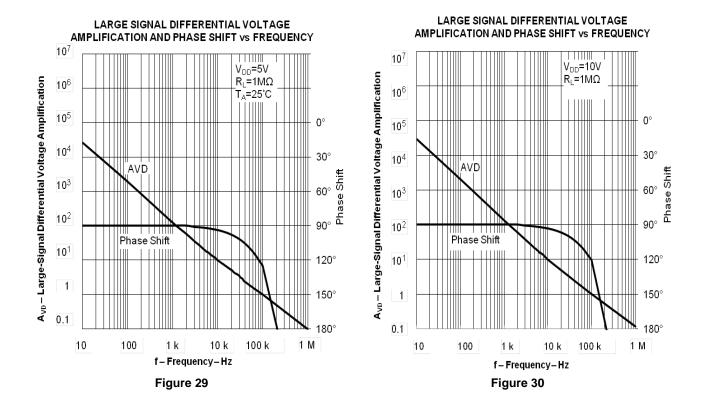


Figure 25

1000



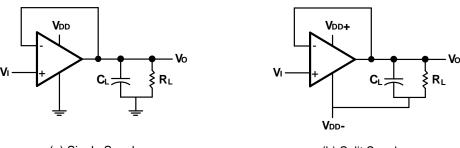




### **Application Information**

#### Parameter measurement circuits

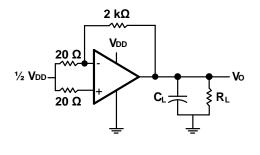
Because the TLC271 is optimized for single-supply operation, circuit configurations used for the various tests can present some difficulties since the input signal must be offset from ground. This issue can be avoided by testing the device with split supplies and the output load tied to the negative rail. Example circuits are shown below.

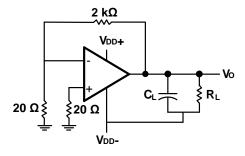


(a) Single Supply



#### Figure 31 Measurement circuit with either single or split supply

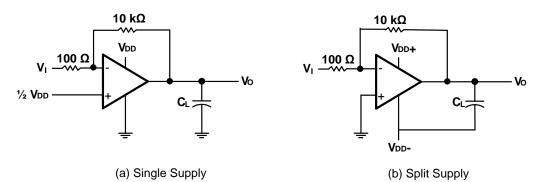




(a) Single Supply

(b) Split Supply

#### Fig 32 Noise measurement with single or split supply







#### **Application Notes**

#### **Offset Voltage Nulling Circuit**

The TLC27L1 offers external input offset null control. Nulling of the input off set voltage may be achieved by adjusting a  $100-k\Omega$  potentiometer connected between the offset null terminals with the wiper connected as shown in Figure 31.

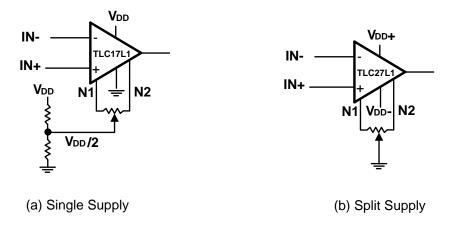


Figure 31 Offset Nulling Circuits

#### Input Bias Current – Error Protection

The TLC27L1 has an extremely high input impedance. To use the inputs as a high impedance node, for example, greater than100K, or to accurately measure bias current, it is necessary to place a guard ring around the input pins and drive the ring to a potential equivalent to the common mode input voltage. In many cases this common mode potential may exist as a part of the feedback circuit and can be obtained from one of the appropriate nodes. In the case for the SO8 package, pin 4 is connected to ground or Vdd-. Input pins 2 and 3 are normally well above the voltage on pin 4, so a large potential voltage on the order of several volts is likely between pins 3 and 4. To prevent interference with a 1 pA bias current, the board resistance will need to be in the order of gigaohms to have a minimum impact. The goal is to have the common mode potential on the guard ring, therefore reducing the stray voltage near the input pins to millivolts in normal applications. Any solder flux residue, excess moisture, humidity or board contamination will be detrimental to using the device in a high impedance input mode.

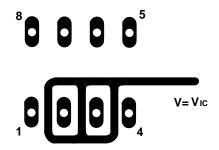


Figure 32 Bias Current Guarding for High Input Impedance Applications



### **Typical Application Circuits**

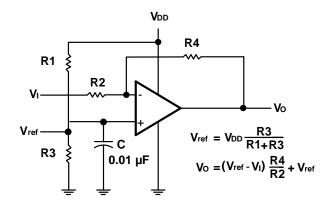
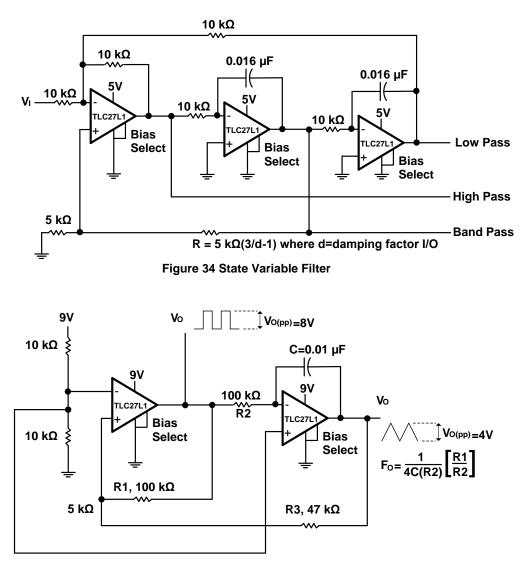


Figure 33 Inverting Amplifier With Voltage Reference







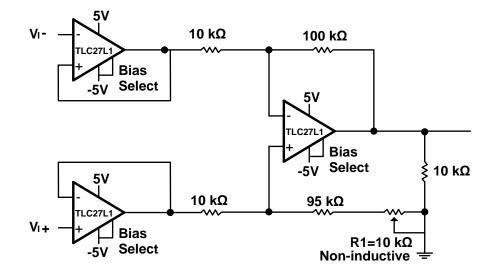


Figure 36 Low Power Instrumentation Amplifier

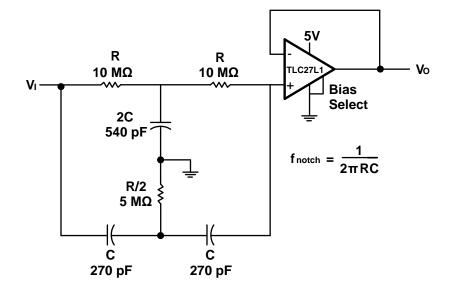


Figure 37 Single Supply Twin-T Notch Filter



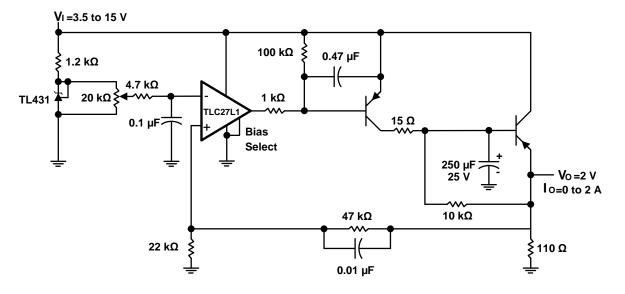
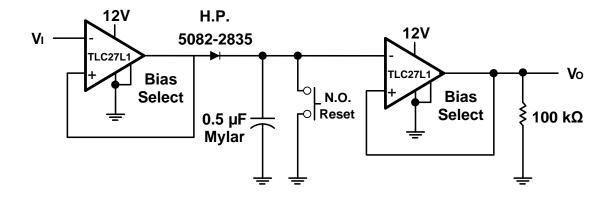


Figure 38 Power Supply



**Figure 39 Positive Peak Detector** 



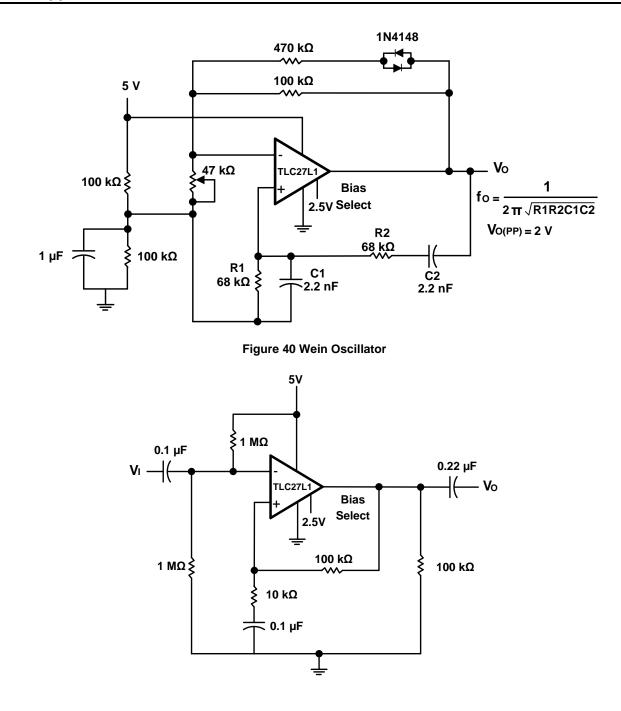
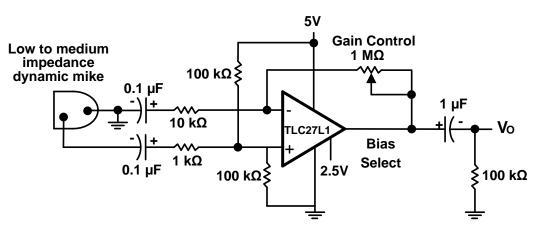


Figure 41 Single-Supply AC Amplifier







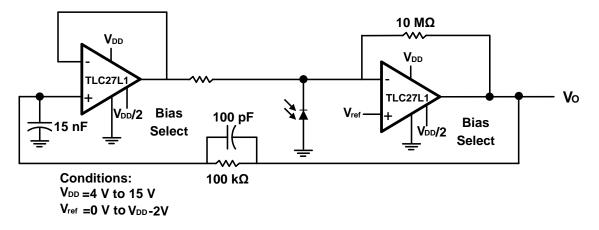


Figure 43 Photo-Diode Amplifier With Ambient Light Rejection

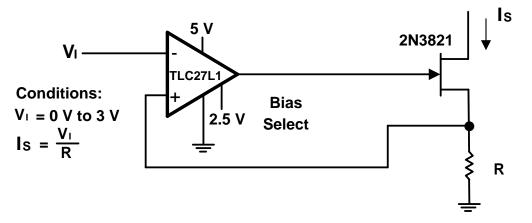


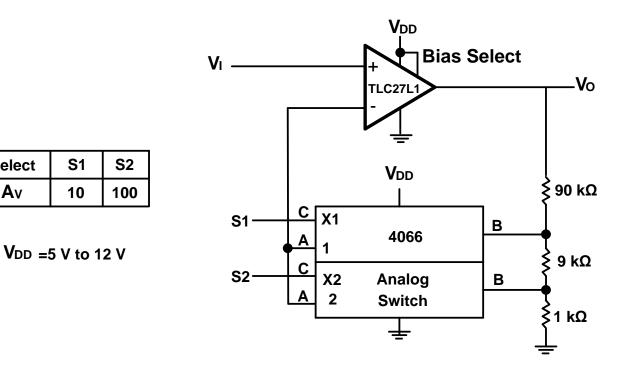
Figure 44 Precision Low-Current Sink



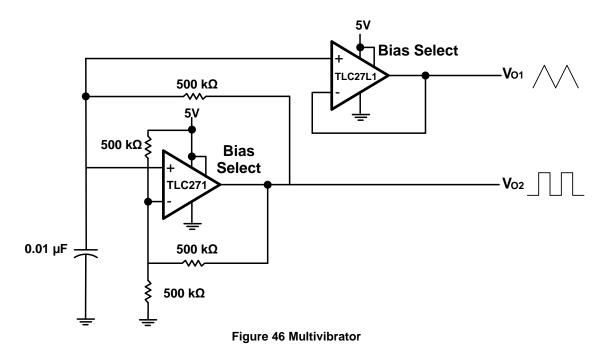
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Av

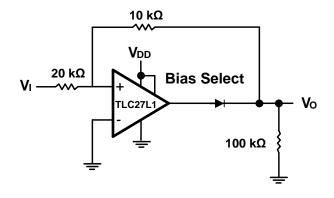
### Typical Application Circuits (cont.)



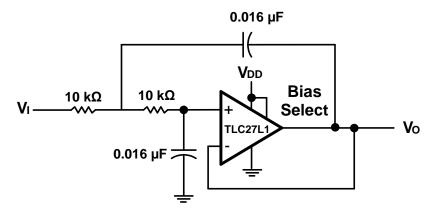
#### Figure 45 Amplifier With Digital Gain Selection











Nomalized to Fc = 1 kHz and R  $_{\rm L}$  = 10 k $\Omega$ 

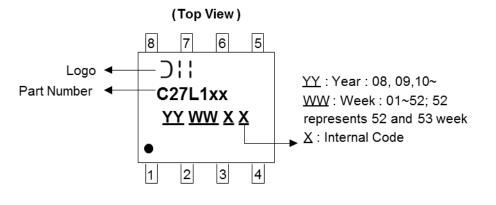
Figure 48 Two-Pole Low-Pass Butterworth Filter



### **Marking Information**

#### SO-8

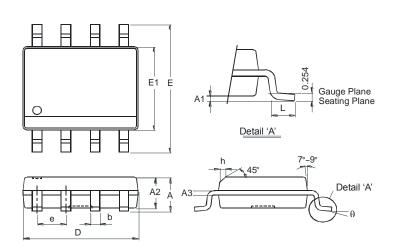
Part mark	Part number
C27L1C	TLC27L1CS
C27L1AC	TLC27L1ACS
C27L1BC	TLC27L1BCS
C27L1I	TLC27L1IS
C27L1AI	TLC27L1AIS
C27L1BI	TLC27L1BIS



#### **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### Package Type: SO-8



	SO-8	
Dim	Min	Max
Α	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
Е	5.90	6.10
E1	3.85	3.95
е	1.27	Тур
h	-	0.35
L	0.62	0.82
θ	0°	8°
All Di	mensions	in mm



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